

DFN1412-6

A new (double) package standard

With its low height, high-performance and large portfolio the DFN1412-6 (SOT1268) gives you a double advantage for your system's diodes and transistors.

Ultra-small double package



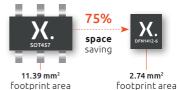
- > Leadless, ultra-small double package
- > Small 1.4 x 1.2 mm footprint, only 0.47 mm high
- > 0.5 mm Pitch
- Surface-Mounted Device (SMD) plastic package
- > AEC-Q101 qualified

Large portfolio



- Standard switching diodes (BAV70SRA & BAW56SRA)
- 100 and 500 mA double transistors (BC847/857/807/817)
- 100 mA digital transistors (RETs - Resistor-Equipped-Transistors)
- > Can replace SOT666, SOT363 or SOT457

Benchmark performance/size



- **>** Excellent thermal performance
- SOT457 performance from a smaller package
- > High P_{tot} capability (500 mW per device)

Application flexibility



- Mobile and wearable
- Space restricted systems



DFN1412-6 Product range

Transistors double							
Polarity	V _{CEO} (V)	I _c (mA)	h _{FE} min	h _{FE} max	f _T min (MHz)		
NPN	45	100	200	450	100	BC847RA	
	45	500	160	400	100	BC817RA	
PNP	45	100	200	450	100	BC857RA	
	45	500	160	400	80	BC807RA	
NPN/PNP	45	100	200	450	100	BC847RAPN	
	45	500	160	160	100/80	BC817RAPN	

RETs 100 mA double								
V _{CEO} (V)	I _c (mA)	Configuration	R1 (kΩ)	R2 (kΩ)	NPN/NPN	NPN / PNP	PNP / PNP	
50	100	R1 = R2	10	10	PRMH11	PRMD3	PRMB11	
			22	22		PRMD2		
			47	47	PRMH2	PRMD12		
		R1 ≠ R2	2.2	47	PRMH10	PRMD10		
			4.7	47	PRMH13	PRMD13		
			10	47	PRMH9			
			22	47		PRMD16		

Switching diodes							
V _R (max)	V _F (max)	@I _F (mA)	I _R max (nA)	@ V _R (V)	t _{rr} max (ns)		
100	1	50	500	80	4	文 文	BAV70SRA
90	1	50	500	80	4	★ ★ → → → → → → → → → → → → → → → → → →	BAW56SRA

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